

RJK60S1DPD

600V - 8A - SJ MOS FET High Speed Power Switching R07DS0853EJ0004 Rev.0.04 Nov 30, 2012

Features

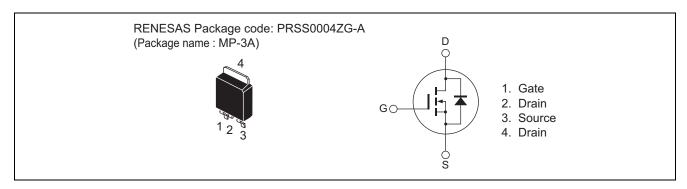
- Superjunction MOSFET
- Low on-resistance

 $R_{DS(on)}=0.84~\Omega$ typ. (at $I_D=2.2A,~V_{GS}=10~V,~Ta=25^{\circ}C)$

• High speed switching

 t_f = 61 ns typ. (at I_D = 2.2 A, V_{GS} = 10 V, R_L = 136 Ω , Rg = 10 Ω , Ta = 25°C)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

				(1a-23 C)
Item		Symbol	Ratings	Unit
Drain to source voltage		V _{DSS}	600	V
Gate to source voltage		V _{GSS}	+30, -20	V
Drain current	Tc = 25°C	I _D Note1,2	8	Α
	Tc = 100°C	I _D Note1,2	5	А
Drain peak current		I _{D (pulse)} Note1	16	А
Body-drain diode reverse drain current		I _{DR} Note1	8	А
Body-drain diode reverse drain peak current		I _{DR (pulse)} Note1	16	А
Avalanche current		I _{AP} Note3	1.1	А
Avalanche energy		E _{AR} Note3	0.066	mJ
Channel dissipation		Pch Note4	31.2	W
Channel to cse thermal impedance		θ с h-с	4.0	°C/W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Limited by Tch max.

- 2. Maximum duty cycle D = 0.5
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C
- 4. Value at Tc = 25°C

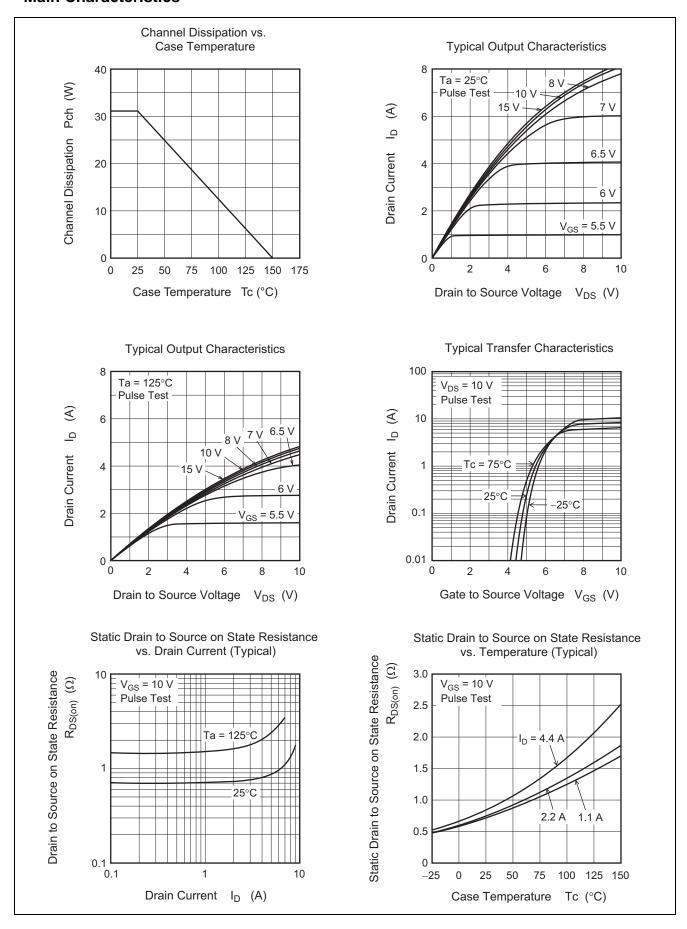
Electrical Characteristics

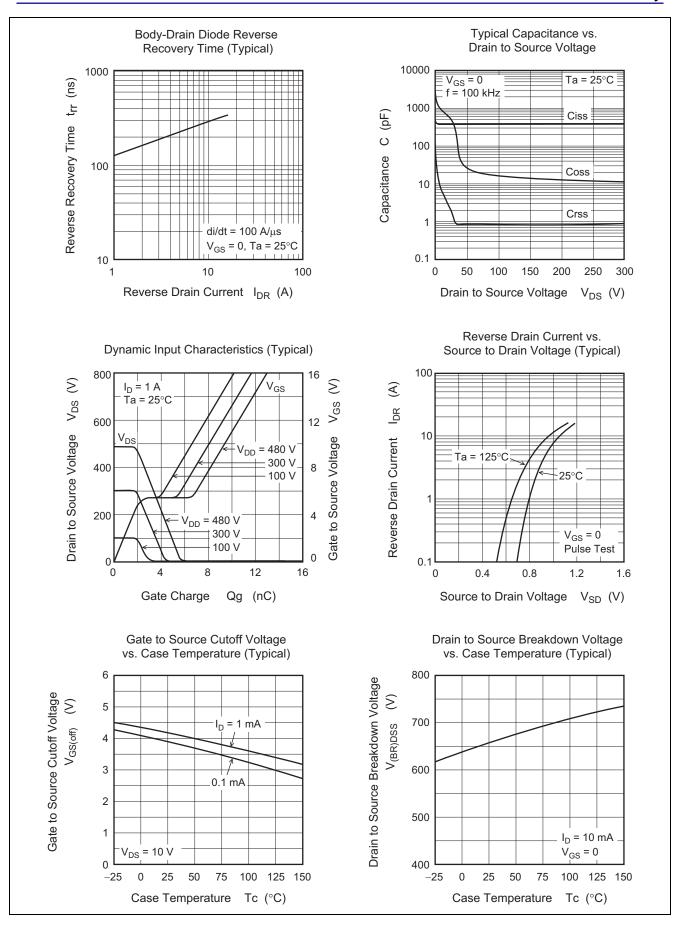
 $(Ta = 25^{\circ}C)$

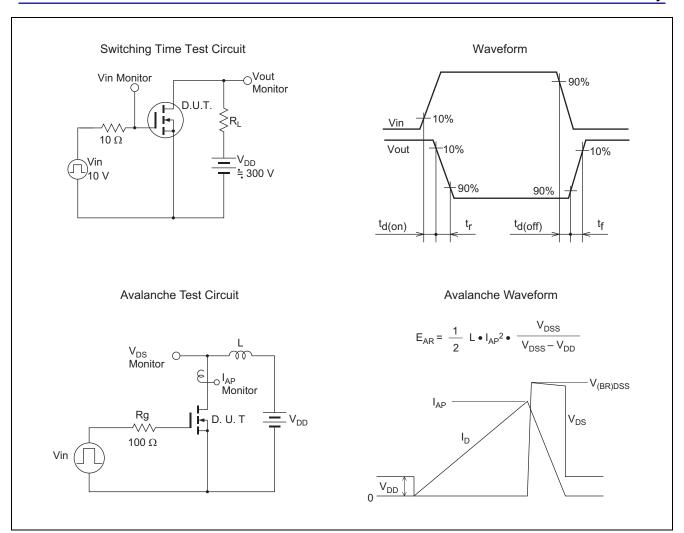
Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Zero gate voltage drain current	I _{DSS}	_	_	1	mΑ	V _{DS} = 600 V, V _{GS} = 0	
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = +30V, -20 V, V_{DS} = 0$	
Gate to source cutoff voltage	$V_{GS(off)}$	3	_	5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	
Static drain to source on state	R _{DS(on)}	_	0.84	1.05	Ω	$I_D = 2.2 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$	
resistance	R _{DS(on)}		2.10	_	Ω	Ta = 150°C	
						$I_D = 2.2 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$	
Gate resistance	Rg	_	3.4		Ω	f = 1 MHz	
						$V_{DS} = 25 \text{ V}, V_{GS} = 0$	
Input capacitance	Ciss		380	_	pF	V _{DS} = 25 V	
Output capacitance	Coss		500	_	pF	V _{GS} = 0 f = 100 kHz	
Reverse transfer capacitance	Crss	_	2.1	_	pF		
Turn-on delay time	t _{d(on)}	_	9	_	ns	I _D = 2.2 A	
Rise time	t _r	_	15	_	ns	$V_{GS} = 10 \text{ V}$ $R_L = 136 \Omega$	
Turn-off delay time	t _{d(off)}		22	_	ns		
Fall time	t _f		61	_	ns	$Rg = 10 \Omega^{Note5}$	
Total gate charge	Qg		9.3	_	nC	V _{DD} = 480 V V _{GS} = 10 V	
Gate to source charge	Qgs		2.1	_	nC		
Gate to drain charge	Qgd		4.5	_	nC	$I_D = 1 A^{Note5}$	
Body-drain diode forward voltage	V_{DF}		1.0	1.6	V	$I_F = 4.4 \text{ A}, V_{GS} = 0^{\text{Note5}}$	
Body-drain diode reverse recovery time	t _{rr}		210	_	ns	I _F = 4.4 A	
Body-drain diode reverse recovery	Irr	_	14.5	_	Α	$V_{GS} = 0$	
current						$di_F/dt = 100 A/\mu s^{Note5}$	
Body-drain diode reverse recovery	Qrr	_	1.7	_	μС		
charge							

Notes: 5. Pulse test

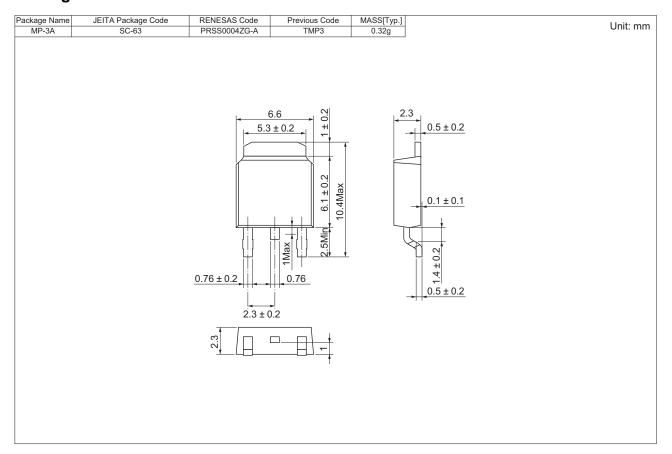
Main Characteristics







Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJK60S1DPD-00#J2	3000 pcs	Taping

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